











SNVS191F-NOVEMBER 2002-REVISED OCTOBER 2016

LM2705

LM2705 Micropower Step-Up DC-DC Converter With 150-mA Peak Current Limit

Features

- 2.2-V to 7-V Input Range
- 150-mA, 0.7-Ω Internal Switch
- Adjustable Output Voltage up to 20 V
- Input Undervoltage Lockout
- 0.01-µA Shutdown Current
- Uses Small Surface-Mount Components
- Small 5-Pin SOT-23 Package

Applications

- LCD Bias Supplies
- White-LED Backlighting
- Handheld Devices
- **Digital Cameras**
- Portable Applications

3 Description

The LM2705 is a micropower step-up DC-DC converter in a small 5-pin SOT-23 package. A fixed-off-time control current-limited. scheme conserves operating current, which results in high efficiency over a wide range of load conditions. The 21-V switch allows for output voltages as high as 20 V. The low 400-ns off-time permits the use of tiny, low-profile inductors and capacitors to minimize footprint and cost in space-conscious portable applications. The LM2705 is ideal for LCD panels requiring low current and high efficiency as well as white-LED applications for cellular phone backlighting. The LM2705 device can drive up to 3 white LEDs from a single Li-Ion battery. The low peakinductor current of the LM2705 makes it ideal for USB applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM2705	SOT-23 (5)	2.90 mm × 1.60 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Typical 20-V Application L 20 V $V_{IN} = Li-Ion$ 68 μH 6 mA 5 1 -R1 SW VIN 510 kΩ C_{IN} LM2705 C_{OUT} $4.7 \mu F$ 1 μF SHDN FΒ R2 **GND** $33 k\Omega$ 2

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4 Revision History

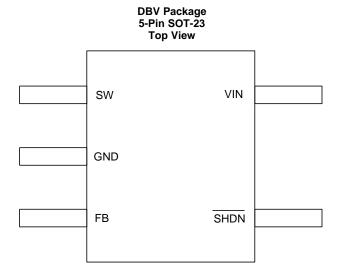
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (May 2013) to Revision F Added Device Information and Pin Configuration and Functions sections, ESD Ratings and Thermal Information tables, Feature Description, Device Functional Modes, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable

Changes from Revision D (May 2013) to Revision E



5 Pin Configuration and Functions



Pin Functions

F	PIN	TYPE	DESCRIPTION
NO.	NAME	ITPE	DESCRIPTION
1	sw	Input	Power switch input. This is the drain of the internal NMOS power switch. Minimize the metal trace area connected to this pin to minimize EMI.
2	GND	_	Ground - tie directly to ground plane.
3	FB	Input	Output voltage feedback input — set the output voltage by selecting values for R1 and R2 using: R1 = R2 \times (V _{OUT} / 1.237 V) $-$ 1
4	SHDN	Input	Active low shutdown - drive this pin to > 1.1 V to enable the device. Drive this pin to < 0.3 V to lace the device in a low-power shutdown.
5	VIN	Input	Analog and power input supply pin

Product Folder Links: LM2705



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)

		MIN	MAX	UNIT
VIN			7.5	V
SW voltage			21	V
FB voltage			2	V
SHDN voltage			7.5	V
Maximum junction temperature,	$T_J^{(3)}$		150	°C
	Soldering (10 seconds)		300	°C
Lead temperature	Vapor phase (60 seconds)		215	°C
	Infrared (15 seconds)		220	°C
Storage temperature, T _{stg}		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) If Military/Aerospace specified devices are required, contact the TI Sales Office/Distributors for availability and specifications.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatio discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Electrostatic discharge	Machine model ⁽²⁾	±200	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM MAX	UNIT
Supply voltage	2.2	7	V
SW voltage, maximum		20.5	V
Junction temperature ⁽¹⁾	-40	125	°C

⁽¹⁾ All limits specified at room temperature and at temperature extremes. All room temperature limits are 100% production tested or specified through statistical analysis. All limits at temperature extremes are specified via correlation using standard statistical quality control (SQC) methods. All limits are used to calculate average outgoing quality level (AOQL).

6.4 Thermal Information

		LM2705	
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT
		5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	164.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	116.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	27.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	13.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	27.3	°C/W

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

Product Folder Links: LM2705

⁽³⁾ The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, R_{0,JA}, and the ambient temperature, T_A. See *Thermal Information* for the thermal resistance. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(MAX)} = (T_{J(MAX)} - T_A) / R_{0,JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature.

⁽²⁾ ESD susceptibility using the machine model is 150 V for SW pin.



6.5 Electrical Characteristics

Unless otherwise specified, specifications apply for T_J = 25°C and V_{IN} = 2.2 V.

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX (1)	UNIT		
	Device disabled	FB = 1.3 V		40				
	Device disabled	FB = 1.3 V, -40°C to 125°C			70			
I_Q	Device enabled	FB = 1.2 V		235		μΑ		
	Device enabled	FB = 1.2 V, -40°C to 125°C			300			
	Shutdown	SHDN = 0 V		0.01	2.5			
	Foodbook trip point			1.237		V		
V_{FB}	Feedback trip point	-40°C to 125°C	1.189		1.269	V		
	Outlink assessed Parts			150		0		
CL	Switch current limit	-40°C to 125°C	100		180	mA		
•	ED als bles someon	FB = 1.23 V ⁽³⁾		30		4		
В	FB pin bias current	FB = 1.23 V, -40°C to 125°C ⁽³⁾			120	nA		
V _{IN}	Input voltage	-40°C to 125°C	2.2		7	V		
R _{DSON}	Outlieb D			0.7		_		
	Switch R _{DSON}	-40°C to 125°C			1.6	Ω		
T _{OFF}	Switch off time			400		ns		
		SHDN = V _{IN} , T _J = 25°C		0	80			
SD	SHDN pin current	SHDN = V _{IN} , T _J = 125°C		15		nA		
		SHDN = GND		0				
L	Switch leakage current	V _{SW} = 20 V		0.05	5	μA		
UVP	Input undervoltage lockout	ON/OFF threshold		1.8		V		
V _{FB} hysteresis	Feedback hysteresis			8		mV		
	OUDN			0.7				
SHDN	SHDN low	-40°C to 125°C			0.3	V		
threshold	OUDN bish			0.7				
	SHDN high	-40°C to 125°C	1.1					

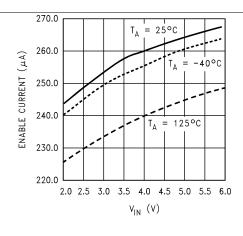
⁽¹⁾ All limits specified at room temperature and at temperature extremes. All room temperature limits are 100% production tested or specified through statistical analysis. All limits at temperature extremes are specified via correlation using standard statistical quality control (SQC) methods. all limits are used to calculate average outgoing quality level (AOQL).

⁽²⁾ Typical numbers are at 25°C and represent the most likely norm.

⁽³⁾ Feedback current flows into the pin.

TEXAS INSTRUMENTS

6.6 Typical Characteristics



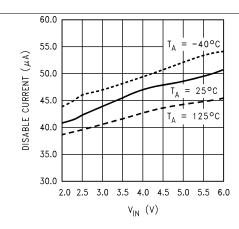


Figure 1. Enable Current vs V_{IN} (Device Switching)

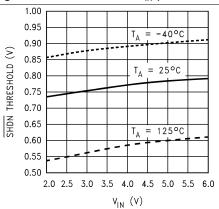


Figure 2. Disable Current vs V_{IN} (Device Not Switching)

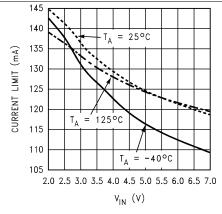


Figure 3. SHDN Threshold vs V_{IN}

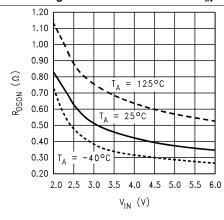


Figure 4. Switch Current Limit vs V_{IN}

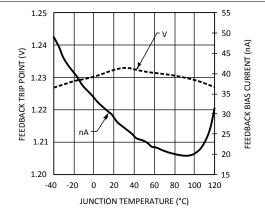
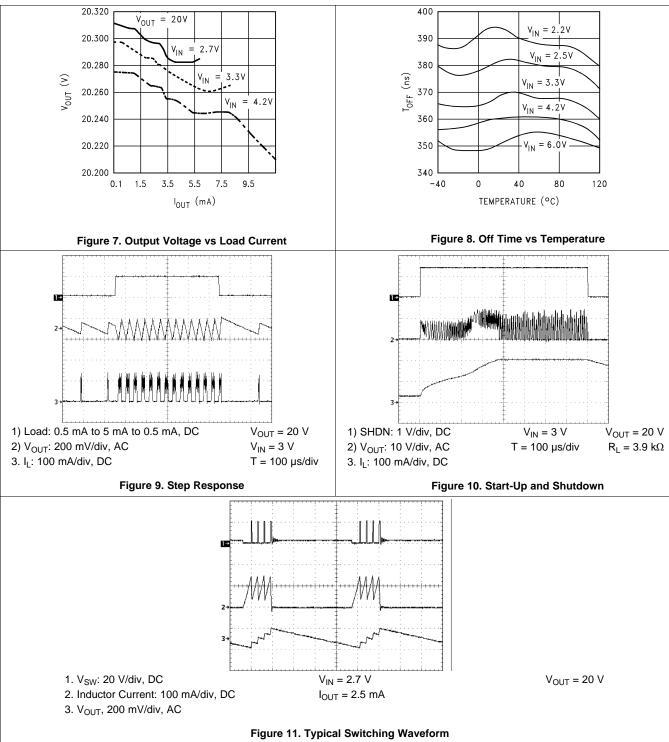


Figure 5. Switch $R_{\rm DSON}$ vs $V_{\rm IN}$

Figure 6. FB Trip Point and FB Pin Current vs Temperature



Typical Characteristics (continued)



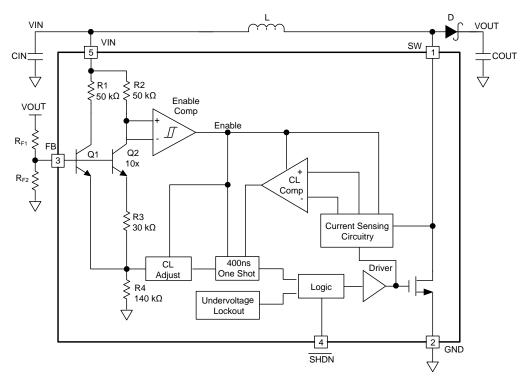


7 Detailed Description

7.1 Overview

The LM2705 is a small boost converter utilizing a constant off time architecture. The device can provide up to 20.5 V at the output with up to 150 mA of peak switch current.

7.2 Functional Block Diagram



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7.3 Feature Description

The LM2705 device features a constant off-time control scheme. Operation can be best understood by referring to *Functional Block Diagram* and Figure 11. Transistors Q1 and Q2 and resistors R3 and R4 of *Functional Block Diagram* form a bandgap reference used to control the output voltage. When the voltage at the FB pin is less than 1.237 V, the Enable Comp in *Functional Block Diagram* enables the device, and the NMOS switch is turned on pulling the SW pin to ground. When the NMOS switch is on, current begins to flow through inductor L while the load current is supplied by the output capacitor C_{OUT}. Once the current in the inductor reaches the current limit, the CL comp trips, and the 400-ns one shot turns off the NMOS switch. The SW voltage then rises to the output voltage plus a diode drop, and the inductor current begins to decrease as shown in Figure 11. During this time the energy stored in the inductor is transferred to C_{OUT} and the load. After the 400-ns off-time the NMOS switch is turned on, and energy is stored in the inductor again. This energy transfer from the inductor to the output causes a stepping effect in the output ripple as shown in Figure 11.

This cycle is continued until the voltage at FB reaches 1.237 V. When FB reaches this voltage, the Enable Comp disables the device, turning off the NMOS switch and reducing the I_Q of the device to 40 μ A. The load current is then supplied solely by C_{OUT} indicated by the gradually decreasing slope at the output as shown in Figure 11. When the FB pin drops slightly below 1.237 V, the Enable Comp enables the device and begins the cycle described previously.

7.4 Device Functional Modes

The SHDN pin can be used to turn off the LM2705 and reduce the I_Q to 0.01 μ A. In shutdown mode the output voltage is a diode drop lower than the input voltage.



8 Application and Implementation

NOTE

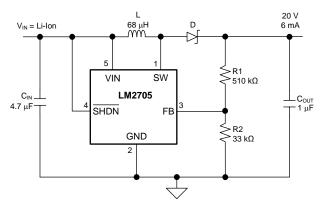
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM2705 is a 20-V boost designed for low power boost applications. Typical input voltage range makes this ideal for standard single cell Li+ batteries or 2 to 4 series alkaline batteries.

8.2 Typical Application

Figure 12 shows a typical Li+ voltage range to 20-V application. The 68-μH inductor allows for a low ripple current and high light-load efficiency.



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Figure 12. Typical 20-V Application

8.2.1 Design Requirements

For typical DC-DC converter applications, use the parameters listed in Table 1.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage	2.5 V to 4.2 V
Output voltage	12 V
Output current	up to 8 mA
Inductor	33 μH

8.2.2 Detailed Design Procedure

8.2.2.1 Inductor Selection - Boost Regulator

The appropriate inductor for a given application is calculated using Equation 1:

$$L = \left(\frac{V_{OUT} - V_{IN(min)} + V_{D}}{I_{CL}}\right) T_{OFF}$$

where

- V_D is the Schottky diode voltage
- I_{CL} is the switch current limit found in the *Typical Characteristics*

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T_{OFF} is the switch off time

(1)

When using this equation be sure to use the minimum input voltage for the application, such as for battery powered applications. For the LM2705 constant-off time control scheme, the NMOS power switch is turned off when the current limit is reached. There is approximately a 100-ns delay from the time the current limit is reached in the NMOS power switch and when the internal logic actually turns off the switch. During this 100-ns delay, the peak inductor current increases. This increase in inductor current demands a larger saturation current rating for the inductor. This saturation current can be approximated by Equation 2:

$$I_{PK} = I_{CL} + \left(\frac{V_{IN(max)}}{L}\right) 100 \text{ ns}$$
(2)

Choosing inductors with low ESR decrease power losses and increase efficiency.

Take care when choosing an inductor. For applications that require an input voltage that approaches the output voltage, such as when converting a Li-Ion battery voltage to 5 V, the 400-ns off time may not be enough time to discharge the energy in the inductor and transfer the energy to the output capacitor and load. This can cause a ramping effect in the inductor current waveform and an increased ripple on the output voltage. Using a smaller inductor causes the I_{PK} to increase and increases the output voltage ripple further.

For typical curves and evaluation purposes the DT1608C series inductors from Coilcraft were used. Other acceptable inductors include, but are not limited to, the SLF6020T series from TDK, the NP05D series from Taiyo Yuden, the CDRH4D18 series from Sumida, and the P1166 series from Pulse.

8.2.2.2 Inductor Selection - SEPIC Regulator

Equation 3 can be used to calculate the approximate inductor value for a SEPIC regulator:

$$L2 = 2\left(\frac{V_{OUT} + V_{D}}{I_{CL}}\right)T_{OFF}$$
(3)

The boost inductor, L1, can be smaller or larger but is generally chosen to be the same value as L2. See Figure 23 and Figure 24 for typical SEPIC applications.

8.2.2.3 Diode Selection

To maintain high efficiency, the average current rating of the Schottky diode should be larger than the peak inductor current, I_{PK} . Schottky diodes with a low forward drop and fast switching speeds are ideal for increasing efficiency in portable applications. Choose a reverse breakdown of the Schottky diode larger than the output voltage.

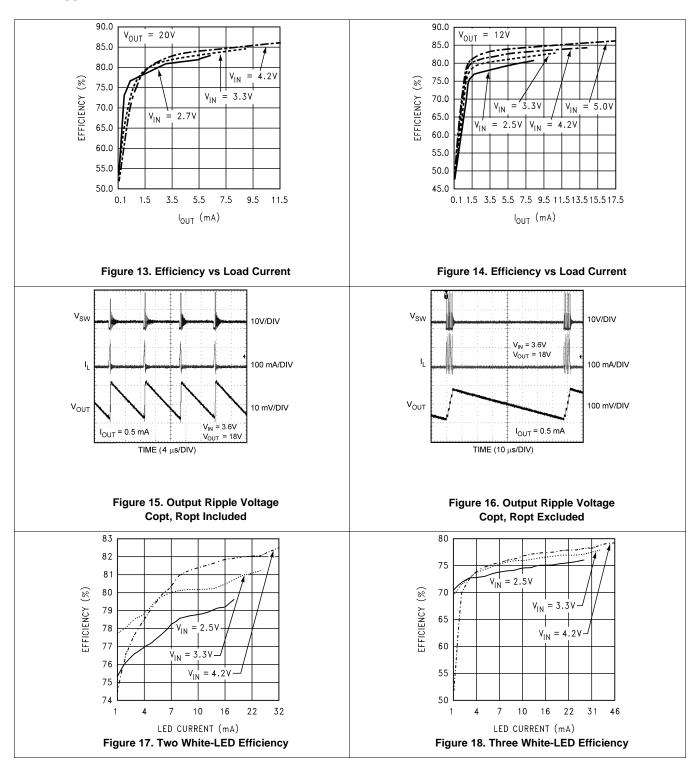
8.2.2.4 Capacitor Selection

Choose low equivalent series resistance (ESR) capacitors for the output to minimize output voltage ripple. Multilayer ceramic capacitors are the best choice. For most applications, a 1-µF ceramic capacitor is sufficient. For some applications a reduction in output voltage ripple can be achieved by increasing the output capacitor. Output voltage ripple can further be reduced by adding a 4.7-pF feed-forward capacitor in the feedback network placed in parallel with RF1 (see *Functional Block Diagram*).

Local bypassing for the input is needed on the LM2705. Multilayer ceramic capacitors are a good choice for this as well. A $4.7-\mu F$ capacitor is sufficient for most applications. For additional bypassing, a 100-nF ceramic capacitor can be used to shunt high frequency ripple on the input.

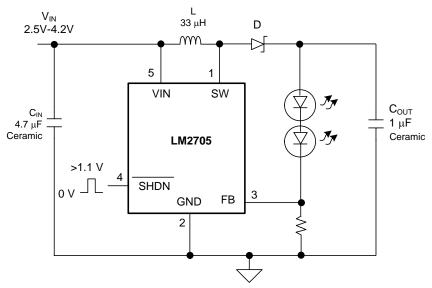


8.2.3 Application Curves



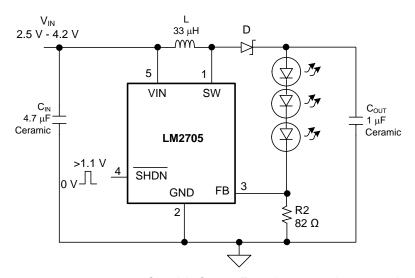


8.3 Additional Applications



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Figure 19. Two White-LED Application

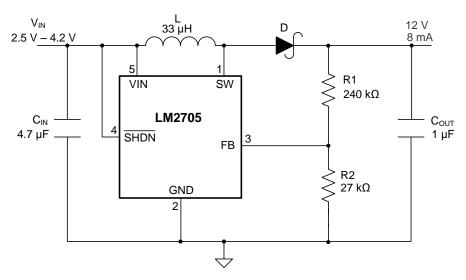


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Figure 20. Three White-LED Application

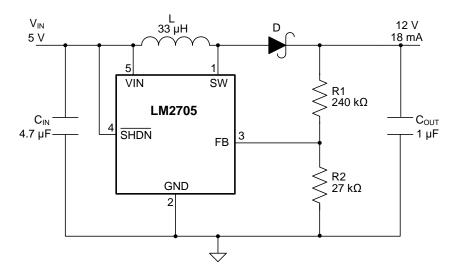


Additional Applications (continued)



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Figure 21. Li-Ion 12-V Application



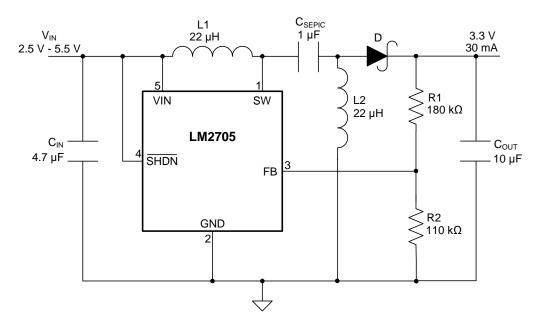
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Figure 22. 5-V to 12-V Application

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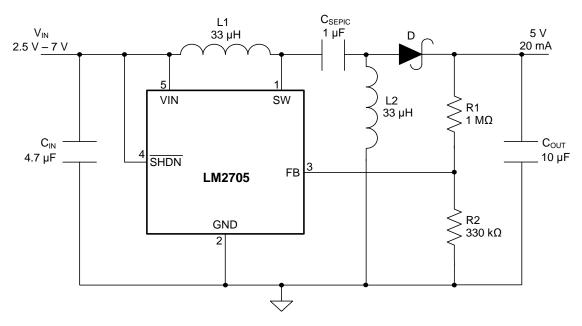


Additional Applications (continued)



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Figure 23. 3.3-V SEPIC Application



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Figure 24. 5-V SEPIC Application



Power Supply Recommendations

The LM2705 is designed to operate from an input voltage supply range from 2.2 V to 7 V. This input supply must be well regulated and capable to supply the required input current. If the input supply is located far from the LM2705, additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

Layout

10.1 Layout Guidelines

The input bypass capacitor C_{IN}, as shown in Figure 25, must be placed close to the device. This reduces copper trace resistance, which effects input voltage ripple of the LM2705 device. For additional input voltage filtering, a 100-nF bypass capacitor can be placed in parallel with C_{IN} to shunt any high frequency noise to ground. The output capacitor, C_{OUT}, must also be placed close to the device. Any copper trace connections for the C_{OUT} capacitor can increase the series resistance, which directly effects output voltage ripple. Keep the feedback network, resistors R1 and R2, close to the FB pin to minimize copper trace connections that can inject noise into the system. The ground connection for the feedback resistor network must connect directly to an analog ground plane. Tie the analog ground plane directly to the GND pin. If no analog ground plane is available, the ground connection for the feedback network must tie directly to the GND pin. Minimize trace connections made to the inductor and Schottky diode to reduce power dissipation and increase overall efficiency.

10.2 Layout Example

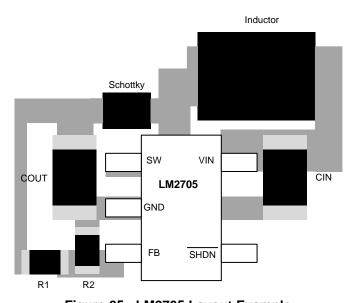


Figure 25. LM2705 Layout Example

Submit Documentation Feedback

Product Folder Links: LM2705



11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer

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11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

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The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: LM2705

www.ti.com 10-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material			Part marking (6)
						(4)	(5)		
LM2705MF-ADJ/NOPB	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S59B
LM2705MF-ADJ/NOPB.A	Active	Production	SOT-23 (DBV) 5	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S59B
LM2705MFX-ADJ/NOPB	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	Call TI Sn	Level-1-260C-UNLIM	-40 to 125	S59B
LM2705MFX-ADJ/NOPB.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	Call TI	Level-1-260C-UNLIM	-40 to 125	S59B

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents Tl's knowledge and belief as of the date that it is provided. Tl bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. Tl has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. Tl and Tl suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

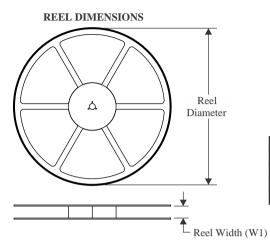
⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

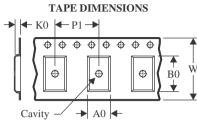
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

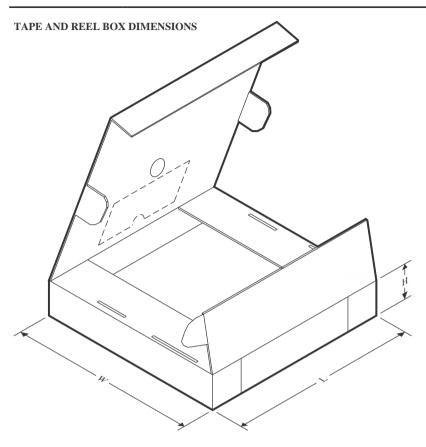


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2705MF-ADJ/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2705MFX-ADJ/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2705MF-ADJ/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM2705MFX-ADJ/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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